Dual N-Channel 200-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

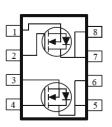
Typical	Applications	
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- · PoE PSE and PD Circuits
- LED Inverter Circuits
- 48V-Input DC/DC Conversion Circuits

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I□ (A)		
200	300 @ V _{GS} = 10V	2.2		
	$340 @ V_{GS} = 4.5V$	2.1		







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter			Symbol	Limit	Units	
Drain-Source Voltage			V_{DS}	200	V	
Gate-Source Voltage				±20	V	
Continuous Drain Current ^a		T _A =25°C		2.2		
Continuous Drain Current	-	T _A =70°C	I _D	1.7	Α	
Pulsed Drain Current ^b				30		
Continuous Source Current (Diode Conduction) a				2.9	Α	
Dawar Dissipation 8		T _A =25°C	P _D	2.1	W	
Power Dissipation ^a	-	T _A =70°C	ı D	1.3	VV	
Operating Junction and Storage Temperature Range			T_J, T_{sta}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	62.5	°C/W		
Maximum Junction-to-Ambient	Steady State	IXOJA	110	C/VV		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

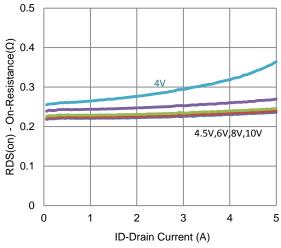
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	uA	
Zoro Coto Voltogo Droin Correct		$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}$			1 uA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	3.5			Α	
Drain Cauras On Basistanas a	r	$V_{GS} = 10 \text{ V}, I_D = 1.7 \text{ A}$			300	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1.4 \text{ A}$			340	11122	
Forward Transconductance a	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 1.7 \text{ A}$		13		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = 1.45 \text{ A}, V_{GS} = 0 \text{ V}$		0.73		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = 100 \text{ V}, V_{GS} = 4.5 \text{ V},$		8.6			
Gate-Source Charge	Q_{gs}	$I_{DS} = 100 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 1.7 \text{ A}$		2.5		nC	
Gate-Drain Charge	Q_{gd}	1D = 1.7 A		4.9			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 100 \text{ V}, R_1 = 58.9 \Omega,$		9			
Rise Time	t _r	$V_{DS} = 100 \text{ V}, \text{ K}_{L} = 36.9 \Omega,$ $I_{D} = 1.7 \text{ A},$		8		no	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		39		ns	
Fall Time	t _f	VGEN = 10 V, NGEN = 0 12		21			
Input Capacitance	C _{iss}			985			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		81		pF	
Reverse Transfer Capacitance	C_{rss}			40			

Notes

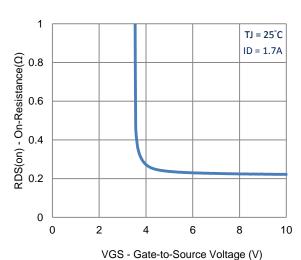
- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

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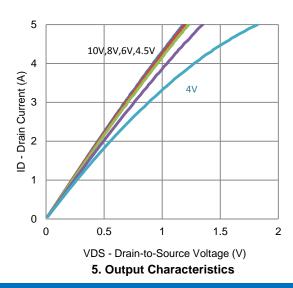
Typical Electrical Characteristics

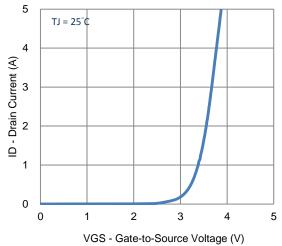


1. On-Resistance vs. Drain Current

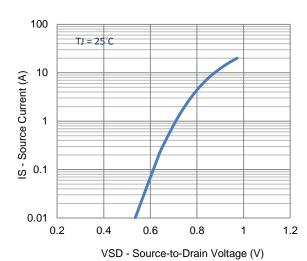


3. On-Resistance vs. Gate-to-Source Voltage

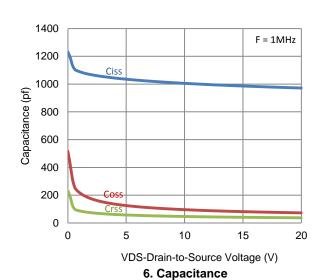




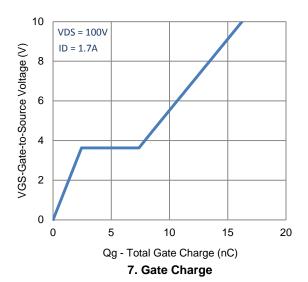
2. Transfer Characteristics

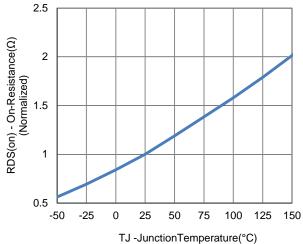


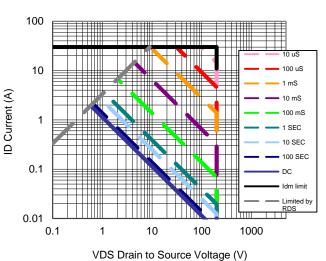
4. Drain-to-Source Forward Voltage



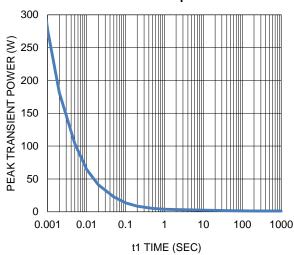
Typical Electrical Characteristics





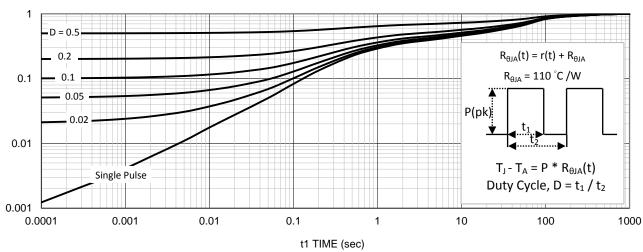






9. Safe Operating Area

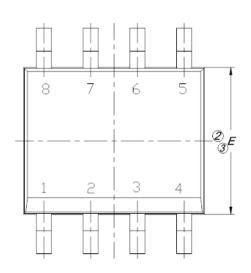
10. Single Pulse Maximum Power Dissipation

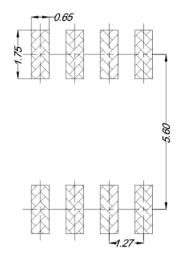


11. Normalized Thermal Transient Junction to Ambient

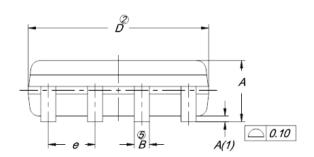
Package Information

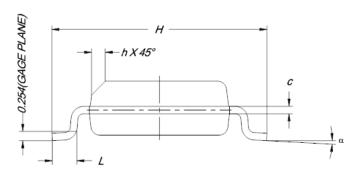
Land Pattern (Only for Reference)





DIM	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
Α	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
Н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		





Note:

- 1. All Dimension Are In mm.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.